National Semiconductor

PRELIMINARY

74LCX240
Low-Voltage Octal Buffer/Line Driver with 5V Tolerant Inputs and Outputs

General Description

The LCX240 is an inverting octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver. The device is designed for low voltage (3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX240 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

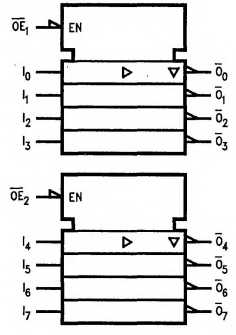
Features

- 5V tolerant inputs and outputs
- Ideal for low power/low noise 2.7V to 3.6V applications
- Power-down static overvoltage protection on inputs and outputs
- Outputs source/sink 24 mA
- Guaranteed simultaneous switching noise level
- Available in SOIC JEDEC, SOIC EIAJ and TSSOP
- Implements patented Quiet Series noise/EMI reduction circuitry
- Functionally compatible with the 74 series 240
- Latchup performance exceeds 300 mA
- ESD performance:
  Human body model > 2000V;
  Machine Model > 250V

Ordering Code: See Section 11

Logic Symbol

IEEE/IEC



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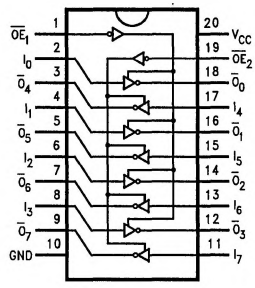
Connection Diagram

Pin Assignment for SOIC and TSSOP



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Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	TRI-STATE® Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Truth Tables

Inputs		Outputs (Pins 12, 14, 16, 18)
$\overline{OE}_1$	I_n	
L	L	H
L	H	L
H	X	Z

Inputs		Outputs (Pins 3, 5, 7, 9)
$\overline{OE}_2$	I_n	
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial Z = High Impedance

	SOIC JEDEC	SOIC EIAJ	TSSOP
Order Number	74LCX240WM 74LCX240WMX	74LCX240SJ 74LCX240SJX	74LCX240MTCX
See NS Package Number	M20B	M20D	MTC20

Preliminary Data: National Semiconductor reserves the right to make changes at any time without notice.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage(V_I)	−0.5V to +7.0V
Output Voltage (V_O)	
Outputs Tri-stated	−0.5V to +7.0V
Outputs Active (Note 2)	−0.5V to V_{CC} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V	−50 mA
DC Output Diode Current (I_{OK})	
V_O < 0V	−50 mA
V_O < V_{CC}	+50 mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or I_{GND})	±100 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Note 1: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Note 2: *I_O Absolute Maximum Rating must be observed.*

Recommended Operating Conditions

Supply Voltage	
Operating	2.0V to 3.6V
Data Retention Only	1.5V to 3.6V
Input Voltage (V_I)	0.0V to 5.5V
Output Voltage (V_O)	
Output in Active State	0V to V_{CC}
Output in "OFF" State	0.0V to 5.5V
Output Current I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.7V to 3.0V	±12 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 0.2, V_{CC} = 3.0V	10 ns/V

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = −40°C to +85°C		Units	Conditions
			Min	Max		
V_{IH}	High Level Input Voltage	2.7–3.6	2.0		V	V_{OUT} ≤ 0.1V or ≥ V_{CC} − 0.1V
V_{IL}	Low Level Input Voltage	2.7–3.6		0.8		
V_{OH}	High Level Output Voltage	2.7–3.6	V_{CC} − 0.2		V	I_{OH} = −100 μA
		2.7	2.2			I_{OH} = −12 mA
		3.0	2.4			I_{OH} = −18 mA
		3.0	2.2			I_{OH} = −24 mA
V_{OL}	Low Level Output Voltage	2.7–3.6		0.2	V	I_{OL} = 100 μA
		3.7		0.4		I_{OL} = 12 mA
		3.0		0.55		I_{OL} = 24 mA
I_I	Input Leakage Current	2.7–3.6		±5.0	μA	0 ≤ V_I ≤ 5.5V
I_{OZ}	TRI-STATE Output Leakage	2.7–3.6		±5.0	μA	0 ≤ V_O ≤ 5.5V; V_I = V_{IH} or V_{IL}
I_{OFF}	Power Off Leakage Current	0		100	μA	V_I or V_O = 5.5V
I_{CC}	Quiescent Supply Current	2.7–3.6		10	μA	V_I = V_{CC} or GND
				±10	μA	3.6 ≤ (V_I, V_O) ≤ 5.5V
ΔI_{CC}	Increase in I_{CC} per Input	2.7–3.6		500	μA	V_{IH} = V_{CC} − 0.6V

AC Electrical Characteristics: See Section 2 for Test Methodology

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Max (Note 2)	
t_{PHL} t_{PLH}	Propagation Delay Data to Output	2.7 3.0–3.6	1.5 1.5	7.5 6.5	ns
t_{PZL} t_{PZH}	Output Enable Time	2.7 3.0–3.6	1.5 1.5	9.0 8.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time	2.7 3.0–3.6	1.5 1.5	8.0 7.0	ns
t_{OSHL} t_{OSLH}	Output to Output Skew (Note 1)	3.0		1.0	ns

Note 1: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Note 2: The maximum AC limits are design targets. Actual performance will be specified upon completion of characterization.

Dynamic Switching Characteristics: See Section 2 for Test Methodology

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$ Typical	Units	Conditions
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.8	V	$C_L = 50$ pF, $V_{IH} = 3.3$V, $V_{IL} = 0$V
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	0.8	V	$C_L = 50$ pF, $V_{IH} = 3.3$V, $V_{IL} = 0$V

Capacitance

Symbol	Parameter	Typical	Units	Conditions
C_{IN}	Input Capacitance	7	pF	V_{CC} = Open $V_I = 0$V or V_{CC}
C_{OUT}	Output Capacitance	8	pF	$V_{CC} = 3.3$V $V_I = 0$V or V_{CC}
C_{PD}	Power Dissipation Capacitance	32	pF	$V_{CC} = 3.3$V $V_I = 0$V or V_{CC} F = 10 MHz